

KSC2331

Low Frequency Amplifier & Medium Speed Switching

- Complement to KSA931
- High Collector-Base Voltage : V_{CBO}=80V
- Collector Current : I_C=700mA
- Collector Dissipation : P_C=1W



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V _{CBO}	Collector-Base Voltage	80	V
V_{CEO}	Collector-Emitter Voltage	60	V
V _{EBO}	Emitter-Base Voltage	8	V
I _C	Collector Current	700	mA
P _C	Collector Power Dissipation	1	W
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C=100\mu A, I_E=0$	80			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, I _B =0	60			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_{E}=10\mu A, I_{C}=0$	8			V
I _{CBO}	Collector Cut-off Current	V_{CB} =60V, I_{E} =0			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	V_{EB} =5V, I_C =0			0.1	μΑ
h _{FE}	DC Current Gain	V_{CE} =2V, I_{C} =50mA	40		240	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =500mA, I _B =50mA		0.2	0.7	V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =500mA, I _B =50mA		0.86	1.20	V
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =50mA	30	50		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		8		pF

h_{FE} Classification

Classification	R	0	Y
h _{FE}	40 ~ 80	70 ~ 140	120 ~ 240

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Typical Characteristics

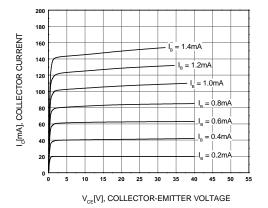


Figure 1. Static Characteristic

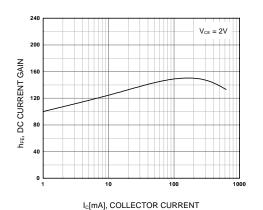


Figure 2. DC current Gain

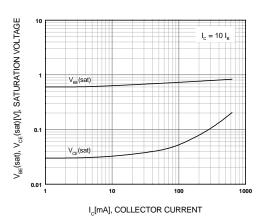


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

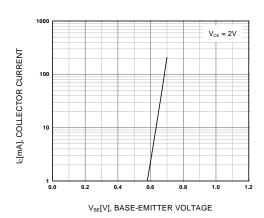


Figure 4. Base-Emitter On Voltage

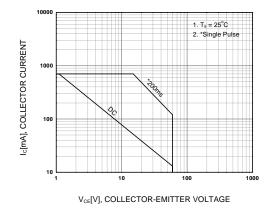


Figure 5. Safe Operating Area

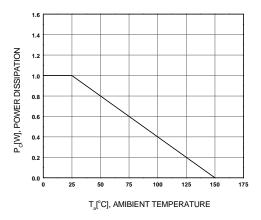


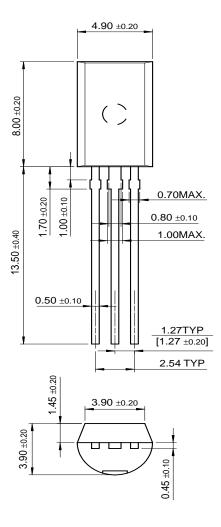
Figure 6. Power Derating

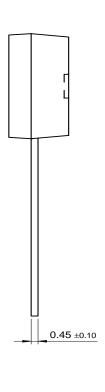
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Package Dimensions

TO-92L





Dimensions in Millimeters

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